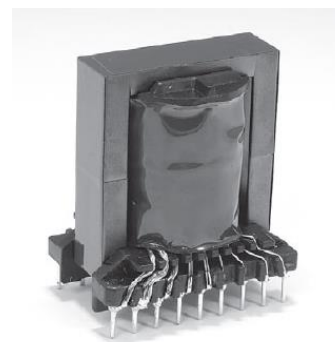
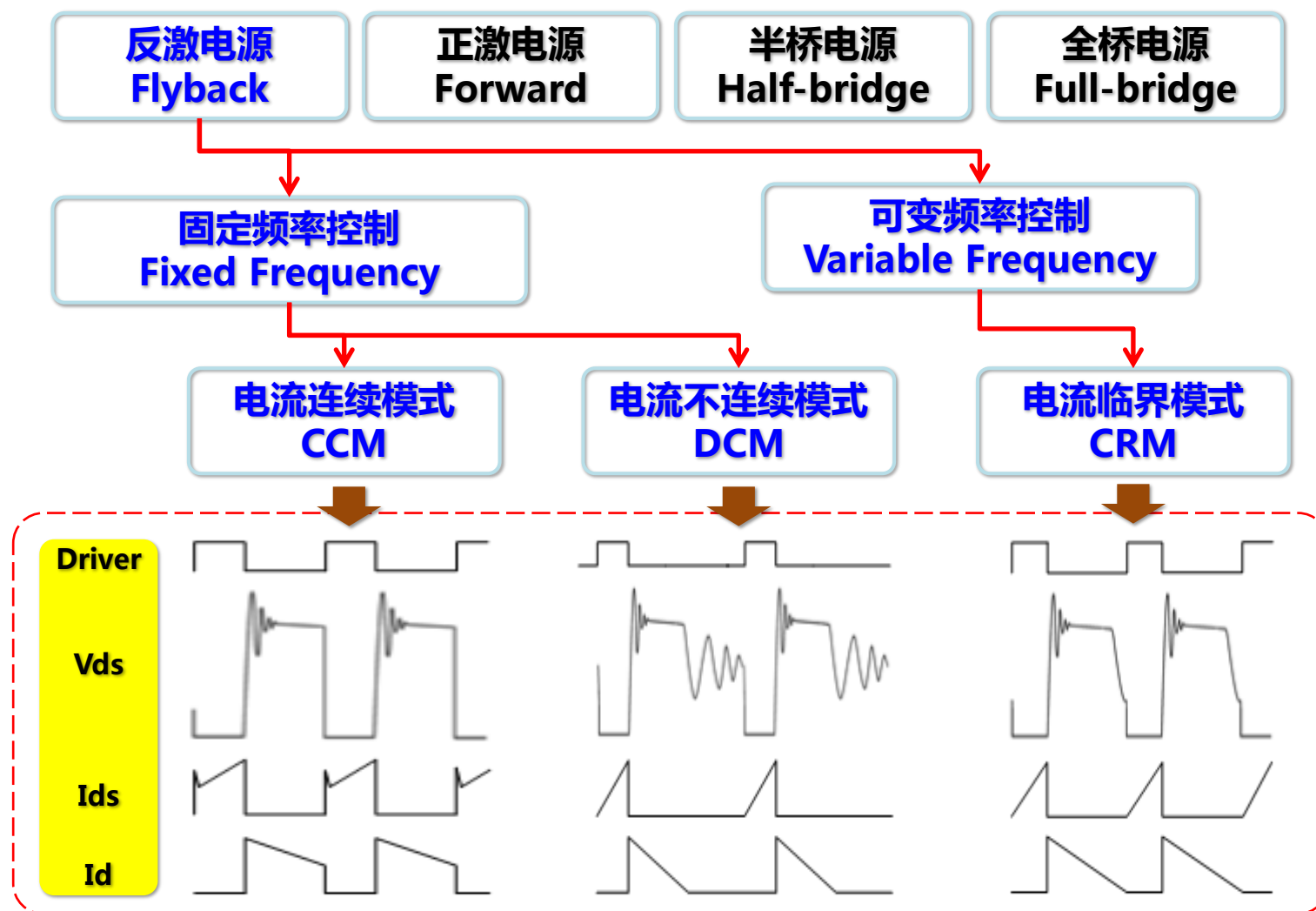


## 小功率高频开关电源变压器的设计计算

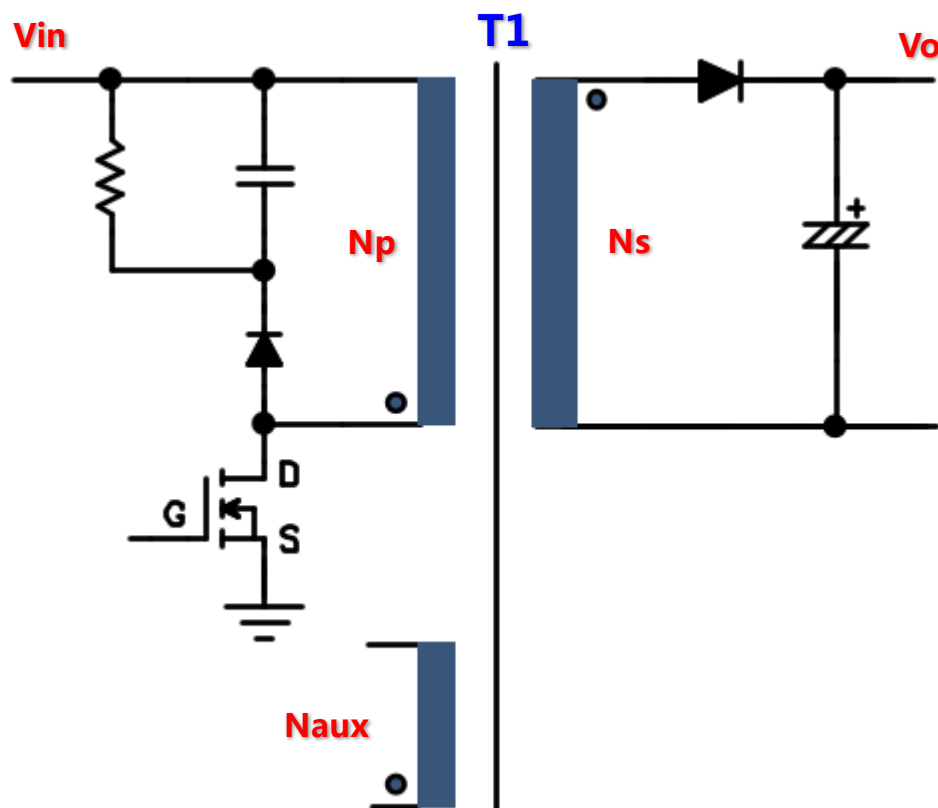
*Advanced Magnetics Technology*



# 小功率AC/DC开关电源的电路拓扑



## 反激电源典型主电路



### 通用原则

- 伏秒数相等原则（磁平衡）
- T1：耦合式储能电感

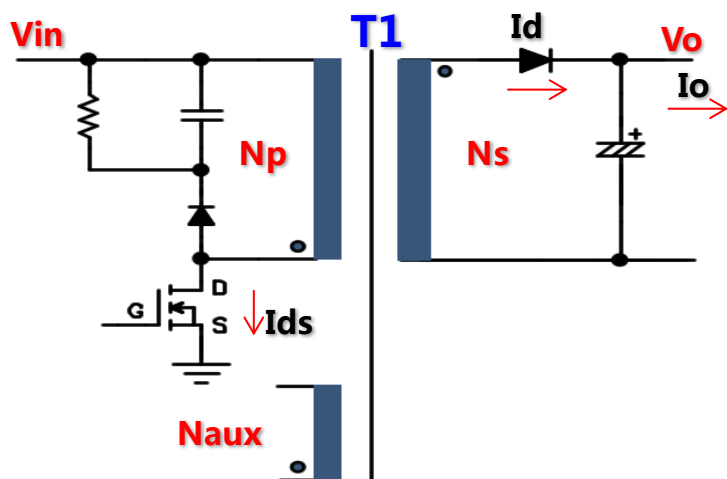
### 两种工作模式

- 固定频率：CCM~DCM
- 准谐振模式：CRM

### 工作模式选定法则

- 电气性能及功能
- 成本
- EMI
- 效率
- 尺寸最优化
- 设计习惯

## CRM反激电源的变压器设计特点



### 伏秒数相等

$$V_{in} \cdot T_{on} = V_o \cdot T_{off}$$

$$V_{in} \cdot D = V_o (1 - D)$$

$$D = \frac{V_o}{V_{in} + V_o}$$

### 电感储能

$$\frac{P_o}{\eta} = \frac{1}{2} \cdot I_{ds}^2 \cdot L_p \cdot f$$

$$P_o = I_o \cdot V_o$$

$$I_{ds}^2 \cdot f = \frac{2P_o}{L_p \eta}$$

### 原边电流

$$I_{ds} = \frac{V_{in}}{L_p} \cdot T_{on} = \frac{V_{in}}{L_p} \cdot \frac{D}{f}$$

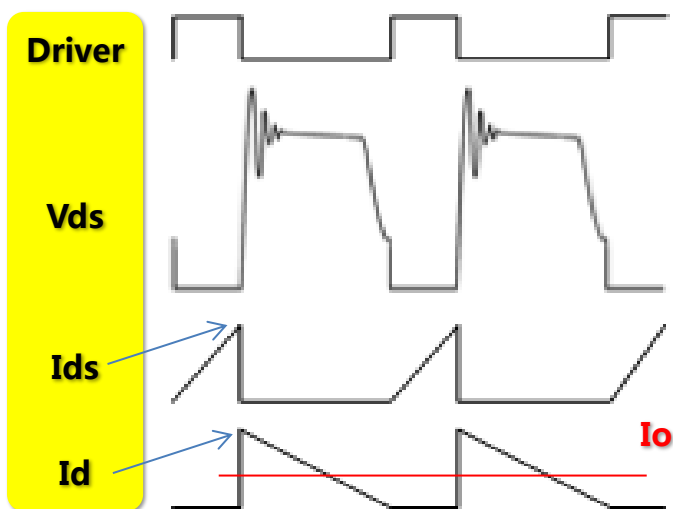
### 副边电流

$$I_o = \frac{1 - D}{2} \cdot I_D$$

### 储能电感续流

$$N_p \cdot I_{DS} = N_s \cdot I_D$$

$$N_p \cdot I_{ds} = N_s \cdot \frac{2I_o}{1 - D}$$



## CRM反激电源的变压器设计特点

### 原副边变比

$$V_C = \frac{V_O \bullet N_P}{N_S}$$

$$V_{ds} = V_{in} + V_C + \alpha(\text{slope})$$

$$N_P / N_S = f(V_{ds}, V_{in}, V_O, \alpha)$$

Example

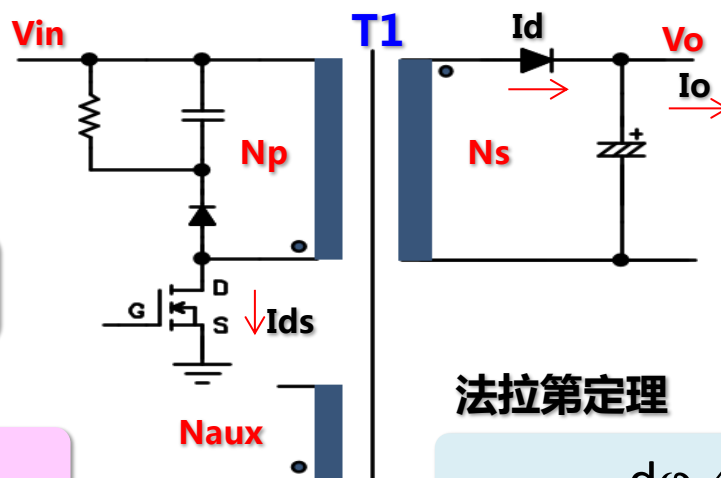
$$V_{ds} = 600 \times 90\% = 540V$$

$$\alpha(\text{slope}) = 50V$$

$$V_O = 24V$$

$$V_{inmax} = 264 \times \sqrt{2} = 373.3V$$

$$N_P / N_S = 4.8625$$



### Np与磁芯选取

$L_P$

电感量定义

$$= \mu_0 \bullet \mu_e \bullet A_e / l_e \bullet N_P^2$$

$$= AL \bullet N_P^2$$

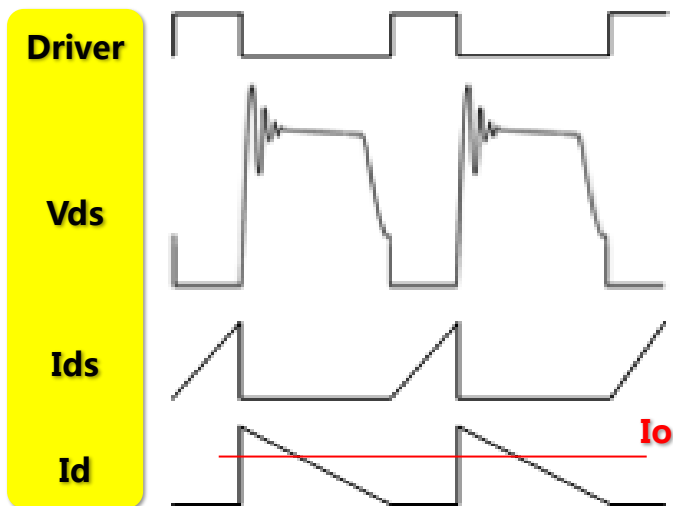
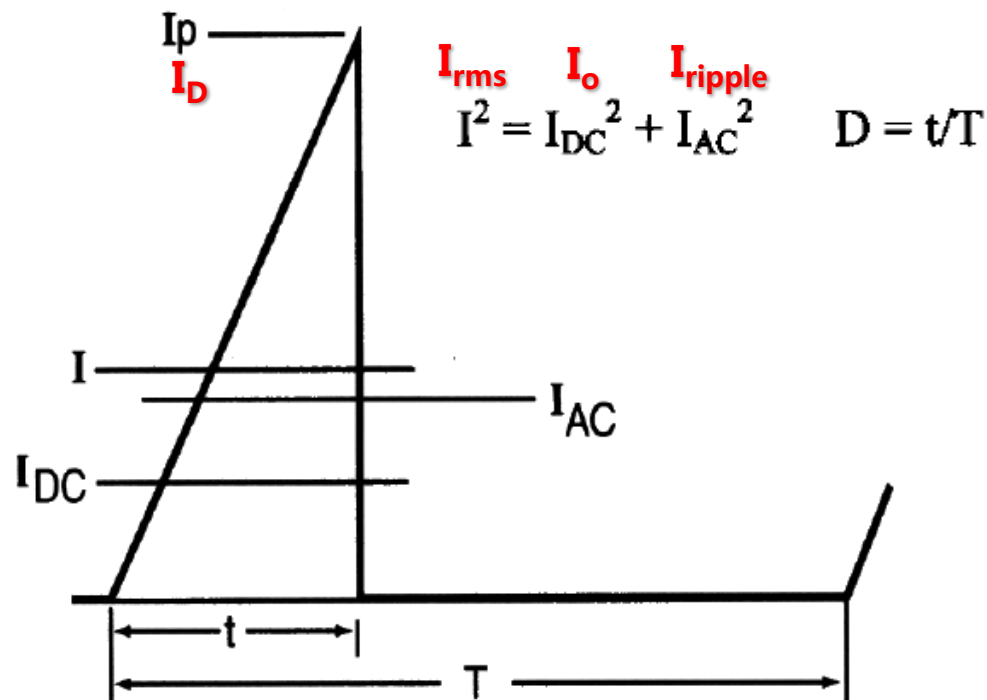
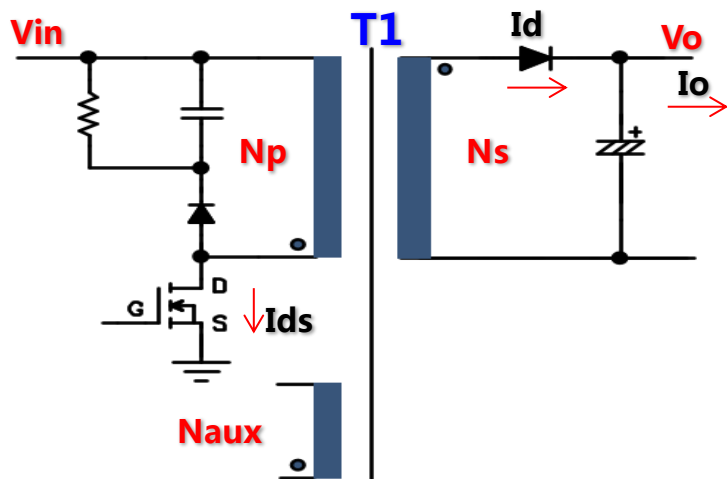
法拉第定理

$$E = N_P \bullet d\phi / dt = N_P \bullet A_e \bullet \Delta B / \Delta t$$

$$E = L_P \bullet di(L_P) / dt = L_P \bullet \Delta I_{DS} / \Delta t$$

$$\Delta B = B_{max} = \frac{L_P \bullet I_{DS}}{N_P \bullet A_e} \rightarrow 360mT$$

## CRM反激电源的变压器设计特点

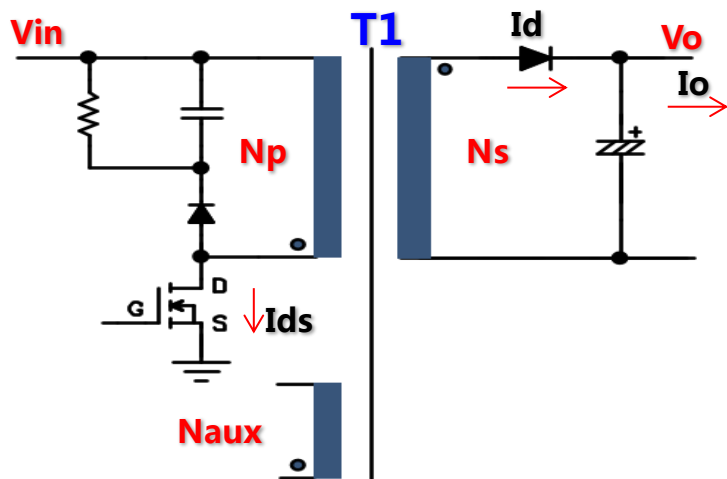


$$I_{DC} = I_p D / 2$$

$$I_{AC} = I_p (D/3 - D^2/4)^{1/2}$$

$$I = I_p (D/3)^{1/2}$$

## CCM反激电源的变压器设计特点



### 伏秒数相等

$$V_{in} \cdot T_{on} = V_o \cdot T_{off}$$

$$V_{in} \cdot D = V_o(1 - D)$$

$$D = \frac{V_o}{V_{in} + V_o}$$

### 电感储能

$$\frac{P_o}{\eta} = \frac{1}{2} \cdot (I_{p2}^2 - I_{p1}^2) \cdot L_p \cdot f$$

$$= \frac{I_{p2} + I_{p1}}{2} \cdot (I_{p2} - I_{p1}) \cdot L_p \cdot f$$

$$= \frac{I_{p2} + I_{p1}}{2} \cdot \Delta I_p \cdot L_p \cdot f$$

$$P_o = I_o \cdot V_o$$

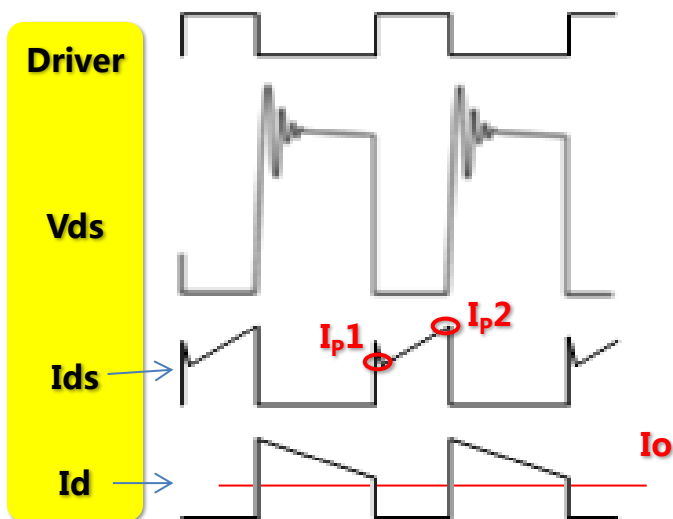
$$(I_{p1} + I_{p2}) \Delta I_p \cdot f = \frac{2P_o}{L_p \eta}$$

### 电感电流

$$\Delta I_p = \frac{V_{in}}{L_p} \cdot T_{on} = \frac{D \cdot V_{in}}{f \cdot L_p}$$

### 副边电流

$$I_o = \frac{N_p}{N_s} \cdot (I_{p1} + I_{p2})(1 - D)$$



## CCM反激电源的变压器设计特点

### 原副边变比

$$V_C = \frac{V_O \cdot N_P}{N_S}$$

$$V_{ds} = V_{in} + V_C + \alpha(\text{slope})$$

$$N_P / N_S = f(V_{ds}, V_{in}, V_O, \alpha)$$

Example

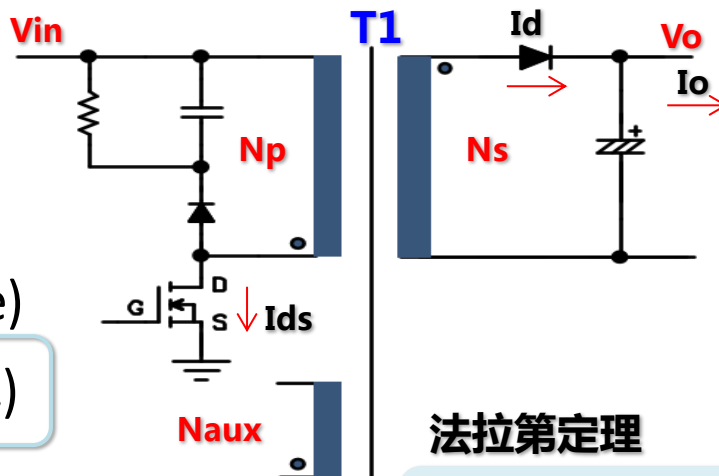
$$V_{ds} = 600 \times 90\% = 540V$$

$$\alpha(\text{slope}) = 50V$$

$$V_O = 24V$$

$$V_{inmax} = 264 \times \sqrt{2} = 373.3V$$

$$N_P / N_S = 4.8625$$



### Np与磁芯选取

$L_P$

电感量定义

$$= \mu_0 \cdot \mu_e \cdot A_e / l_e \cdot N_P^2$$

$$= AL \cdot N_P^2$$

### 法拉第定理

$$E = N_P \cdot d\phi / dt = N_P \cdot A_e \cdot \Delta B / \Delta t$$

$$E = L_P \cdot di(L_P) / dt = L_P \cdot \Delta I_P / \Delta t$$

$$\Delta B = \frac{L_P \cdot I_P}{N_P \cdot A_e}$$

$$\Delta B / B_1 = \Delta I_P / I_{P1}$$

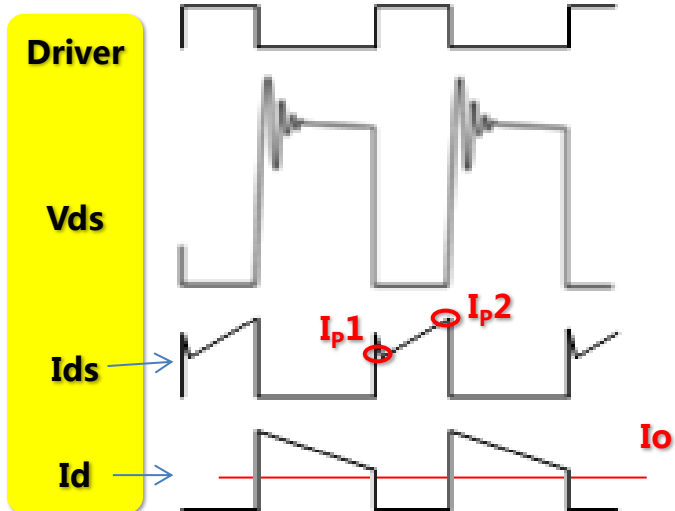
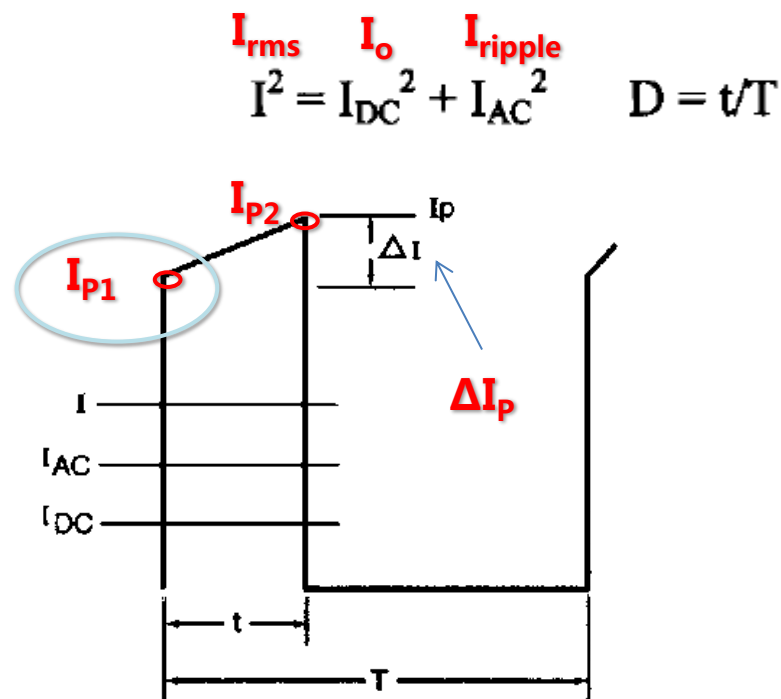
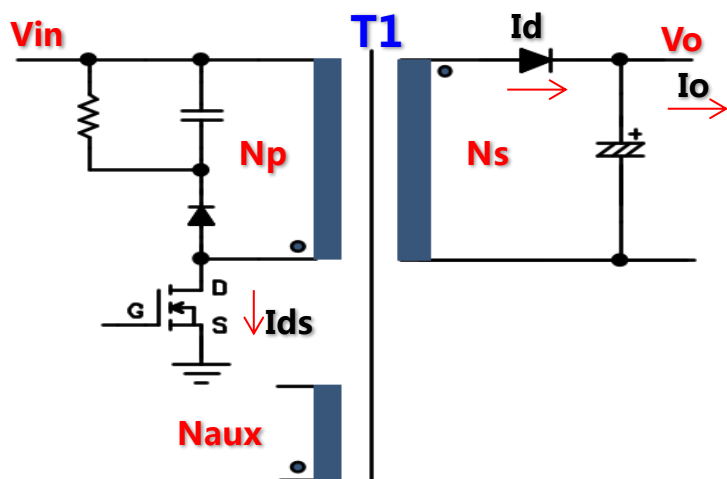
$$\Delta B / B_2 = \Delta B / B_{max} = \Delta I_P / I_{P2}$$

$B_{max}$

➔ 360mT



## CCM反激电源的变压器设计特点

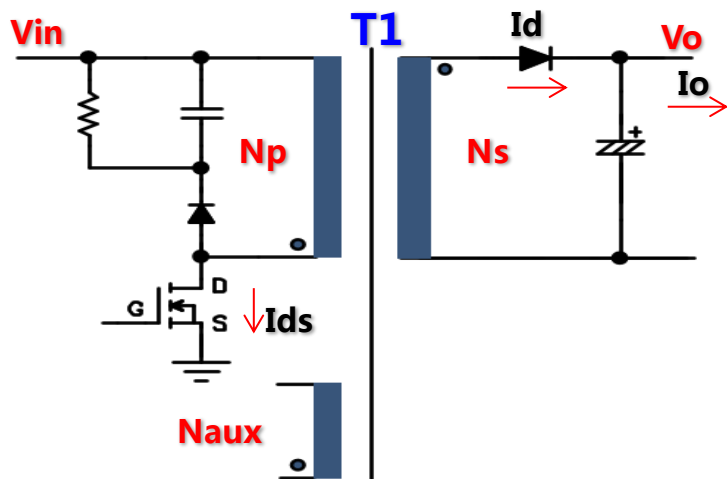


$$I_{DC} = (I_P - \Delta I/2)D$$

$$I_{AC} = (I_P - \Delta I/2)[D(1-D)]^{1/2}$$

$$I = (I_P - \Delta I/2)D^{1/2}$$

## DCM反激电源的变压器设计特点

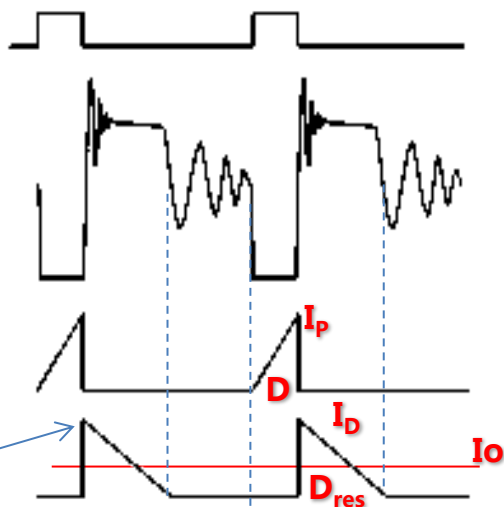


Driver

Vds

Ids

Id



$$V_{in} \bullet D = V_o \bullet D_{res}$$

$$\frac{D}{f} \bullet \frac{V_{in}}{L_P} = I_P$$

$$\frac{I_P^2}{2} \bullet L_P \bullet f = \frac{I_o \bullet V_o}{\eta}$$

$$I_o = D_{res} \bullet \frac{I_D}{2}$$

$$I_P \bullet N_P = I_D \bullet N_S$$

$$\frac{D_{res}}{f} \bullet \frac{V_o}{L_S} = I_D$$

$$\frac{L_P}{N_P^2} = \frac{L_S}{N_S^2}$$

$$V_{ds} = V_{in} + \frac{V_o \bullet N_P}{N_S} + \alpha(\text{spike})$$

伏秒数相等

电感峰值电流

能量存储

直流分量

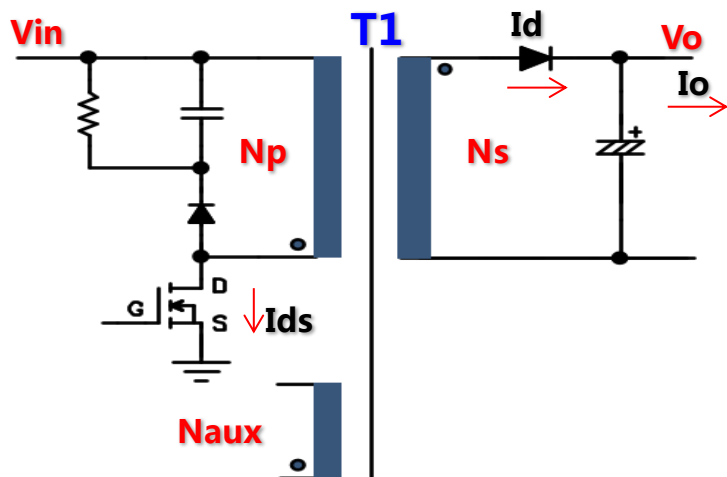
电感续流

电感放电电流

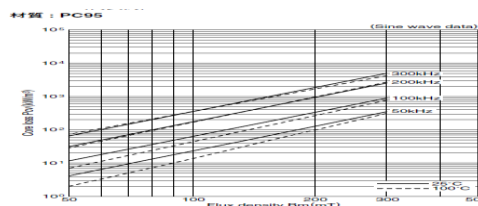
AL值

MOS耐压

## DCM反激电源的变压器设计特点



**任何状态下**  
1) 不能饱和  
2) 损耗 (温升) OK



**Np与磁芯选取**

**电感量定义**

$$L_P = \mu_0 \cdot \mu_e \cdot \frac{A_e}{l_e} \cdot N_P^2$$

$$= AL \cdot N_P^2$$

**法拉第定理**

$$E = N_P \cdot \frac{d\phi}{dt} = N_P \cdot A_e \cdot \frac{\Delta B}{\Delta t}$$

$$E = L_P \cdot \frac{dI(L_P)}{dt} = L_P \cdot \frac{\Delta I_P}{\Delta t}$$

$$\Delta B = \frac{L_P \cdot I_P}{N_P \cdot A_e}$$

$$B_{max} = \Delta B$$

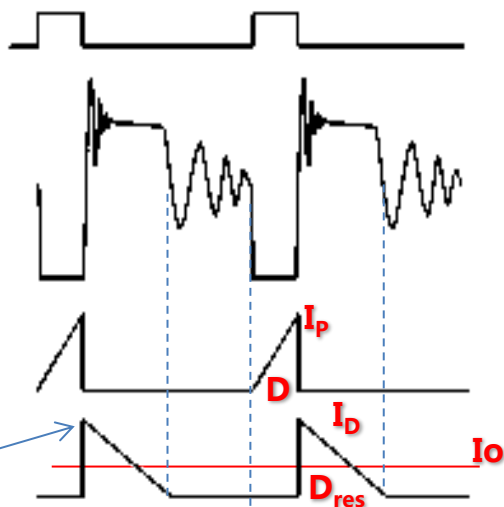
**360mT**

**Driver**

**Vds**

**Ids**

**Id**



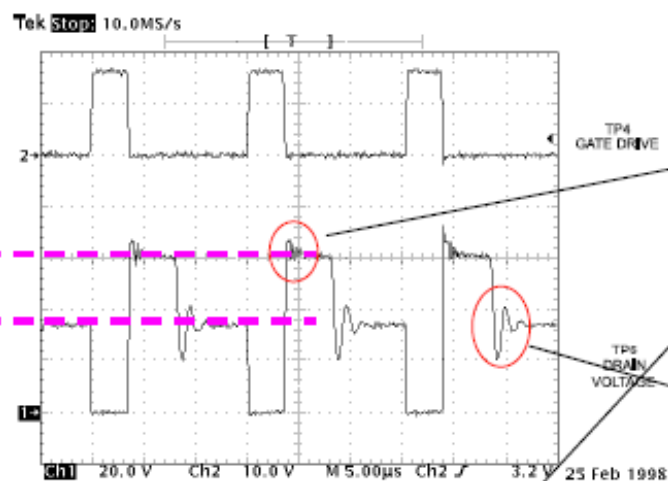
## 影响电压/电流应力的分布参数

陈为老师资料

DCM

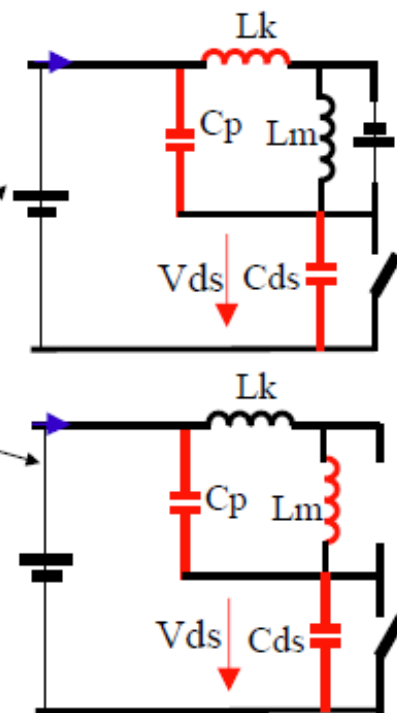
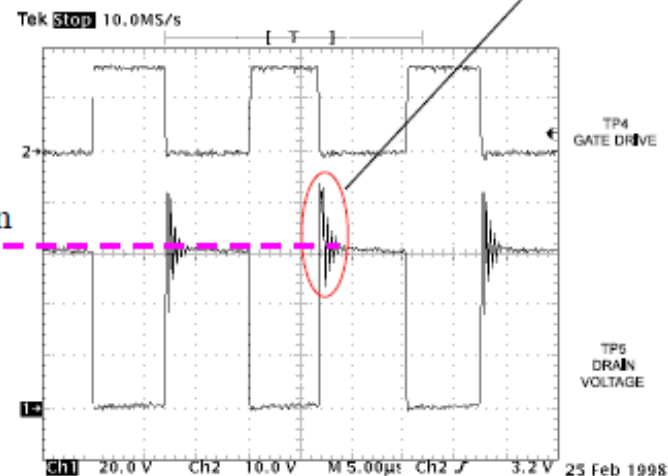
$V_i + V_o \cdot n$

$V_i$



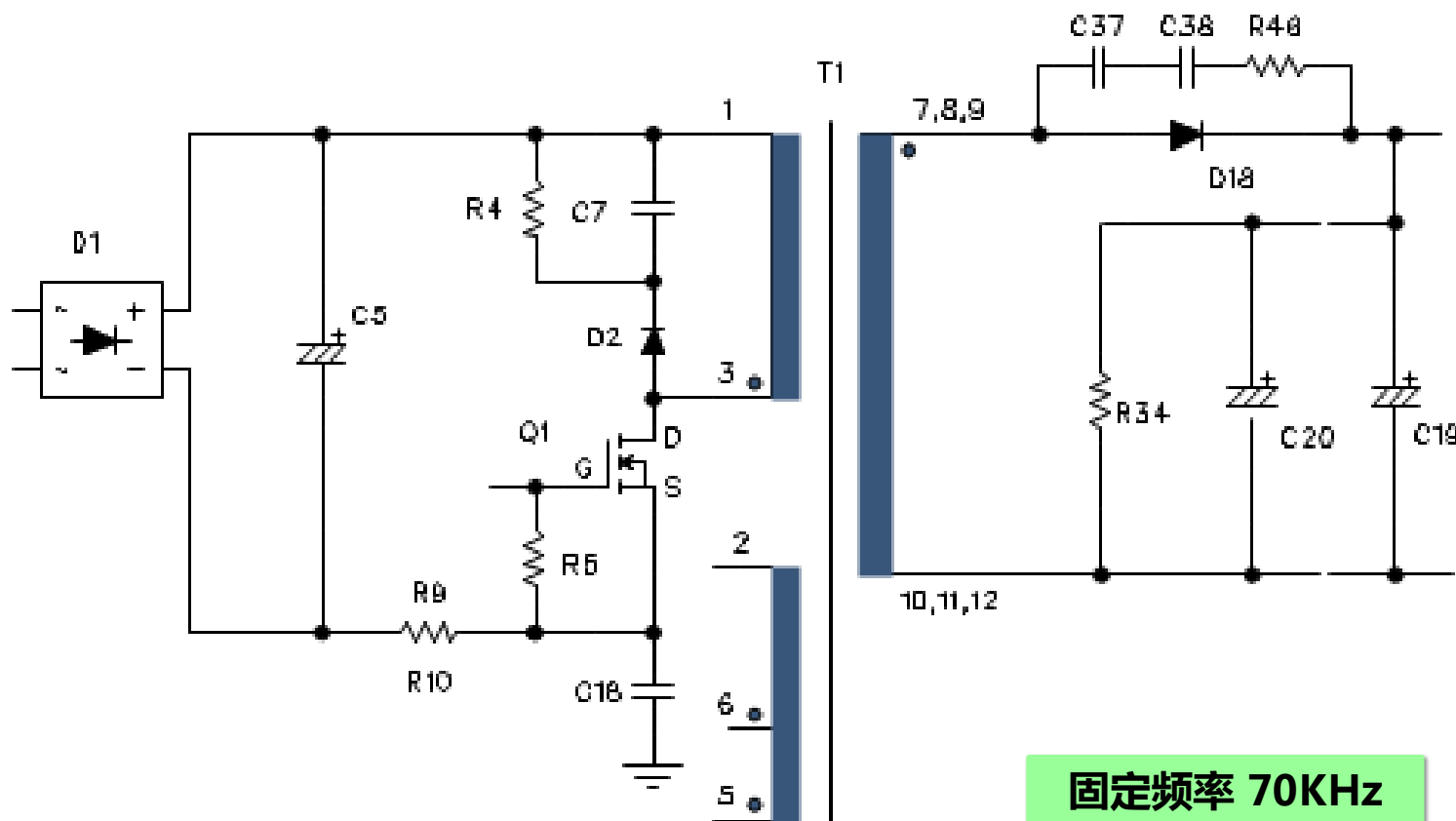
CCM

$V_i + V_o \cdot n$



**Flyback**

## 实例：24V/35W 反激电源主电路

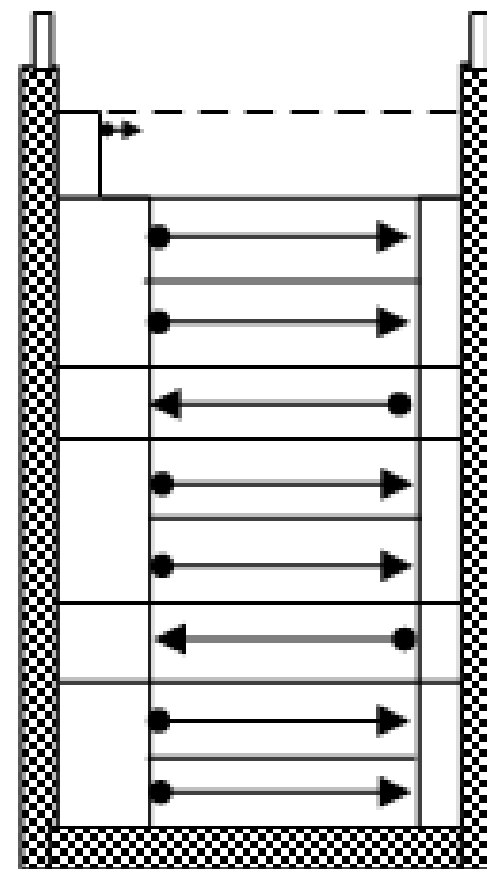
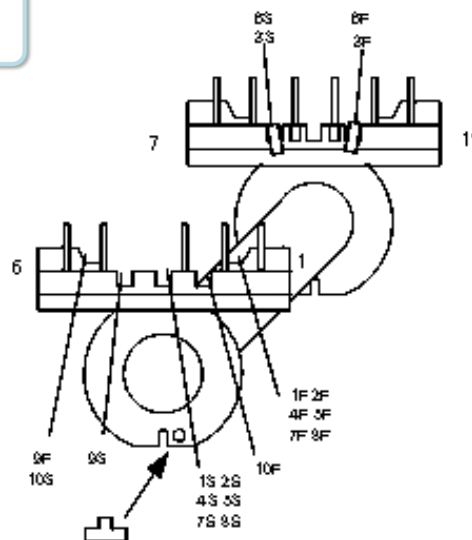
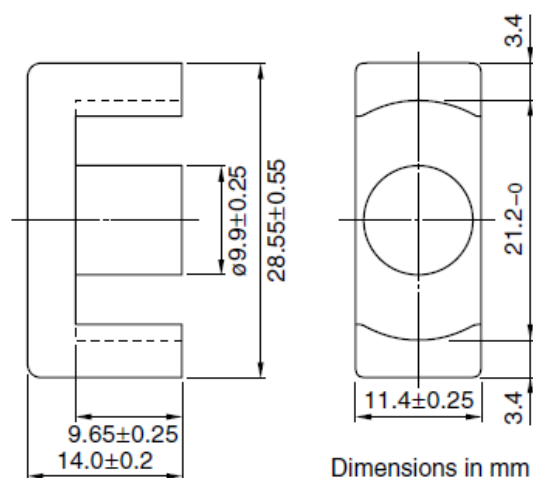


## 实例：24V/35W 70KHz固定频率设计

### 基本要求

输入电压：85~264Vac  
 输出电压：24V±15% 35Wmax  
 工作频率：70KHz  
 MOS耐压：600V  
 整流管耐压：150V  
 电源效率：88% @100~240Vac  
 铁氧体磁芯：EER28 PC40  
 安规距离：5.5mm

C1	mm <sup>-1</sup>	0.78
ℓ <sub>e</sub>	mm	64.0
A <sub>e</sub>	mm <sup>2</sup>	82.1
V <sub>e</sub>	mm <sup>3</sup>	5250
A <sub>cp</sub>	mm <sup>2</sup>	77.0
A <sub>cp min.</sub>	mm <sup>2</sup>	73.1
A <sub>cw</sub>	mm <sup>2</sup>	114
g		28



## 实例：24V/35W 70KHz固定频率设计

现场计算演示

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Frequency (KHz)	Output Power		Rectify Diode			Core Information					Winding Turns		
	Vo	Io	VF	VR	Sparkle	Material	Size	Ae(mm <sup>2</sup> )	Ve(mm <sup>3</sup> )	Rth(°C/W)	Np	Ns	Lp
70	24.0V	1.46A	0.65V	150.0V	20%	PC40	EER28	82.1	5250	22.9	39T	9T	500uH

Input Voltage Range					Device Derating Ratio		Transformer Turns Trying Info.						
CL Point	Minimum	Rating	Max. Rating	Maximum	FET(600V)	Diode	Turn Ratio	Np	15T	16T	17T	18T	19T
Holdup Time	85Vac	100Vac	240Vac	264Vac	92%	85%	Np: Ns	Ns	4T	4T	4T	4T	4T
50V	100V	120V	339V	373V	552.2V	127.5V	4.333 : 1	Err. Range	13%	8%	2%	4%	10%

DC Input	Duty	T <sub>on</sub>	T <sub>Diode on</sub>	Working Conditions in Core			Bobbin	FER28-PB20		Others			
				B <sub>max</sub>	ΔB	P <sub>loss Core</sub>		Pin Side	5.5mm	Period	Ls	AL (nH/N <sup>2</sup> )	Gap (mm)
50V	68.12%	9.73us	4.55us	0.241T	0.152T	0.11W	Margin Tape	Wing Side	3.0mm	14.29us	26.63uH	329	0.62
100V	50.16%	7.17us	6.71us	0.224T	0.224T	0.30W	Wind Space	8.0 mm					
120V	41.80%	5.97us	6.71us	0.224T	0.224T	0.30W	Windings	Total Lays	Wire Para.	Occupation	Max. Φ		Wire Pick
339V	14.78%	2.11us	6.71us	0.224T	0.224T	0.30W	P_Wire	6 Layers	1 para.	1.0 Np	φ 0.200	→	0.16U-2
373V	13.44%	1.92us	6.71us	0.224T	0.224T	0.30W	S_Wire	2 Layers	1 para.	1.0 Np	φ 0.800	→	0.65U-2

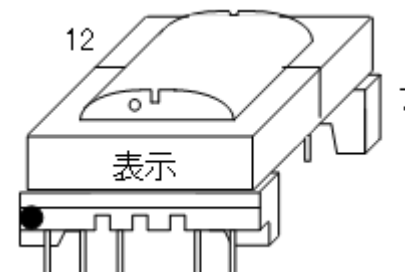
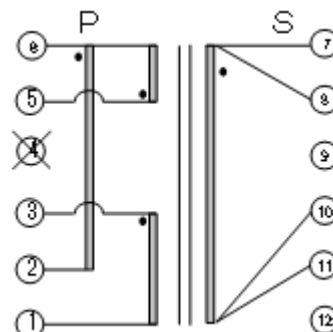
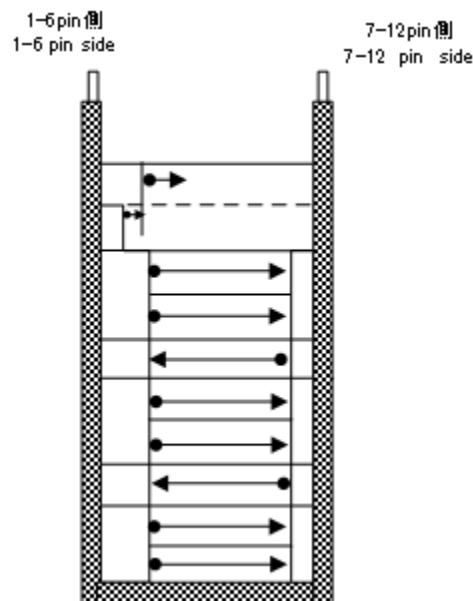
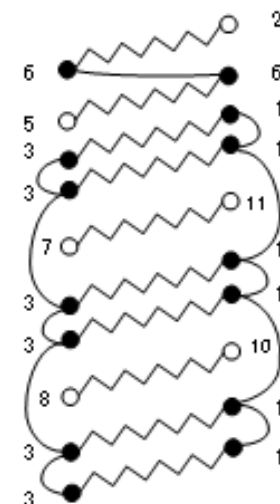
DC Input	Working Condition On Primary Coil							Working Condition On Secondary Coil					
	I1	I2	ΔI	Idc	Iac	Irms	Cur.Density	I1	I2	ΔI	Iac(Ripple)	Irms	Cur.Density
50V	0.57A	1.54A	0.97A	0.72A	0.54A	0.90A	7.47A/mm2	6.68A	2.47A	4.22A	2.24A	2.67A	4.03A/mm2
100V	0.00A	1.43A	1.43A	0.36A	0.46A	0.59A	4.86A/mm2	6.21A	0.00A	6.21A	1.98A	2.46A	3.70A/mm2
120V	0.00A	1.43A	1.43A	0.30A	0.44A	0.54A	4.43A/mm2	6.21A	0.00A	6.21A	1.98A	2.46A	3.70A/mm2
339V	0.00A	1.43A	1.43A	0.11A	0.30A	0.32A	2.64A/mm2	6.21A	0.00A	6.21A	1.98A	2.46A	3.70A/mm2
373V	0.00A	1.43A	1.43A	0.10A	0.29A	0.30A	2.51A/mm2	6.21A	0.00A	6.21A	1.98A	2.46A	3.70A/mm2

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## 实例：24V/35W 70KHz固定频率设计

### 变压器绕制

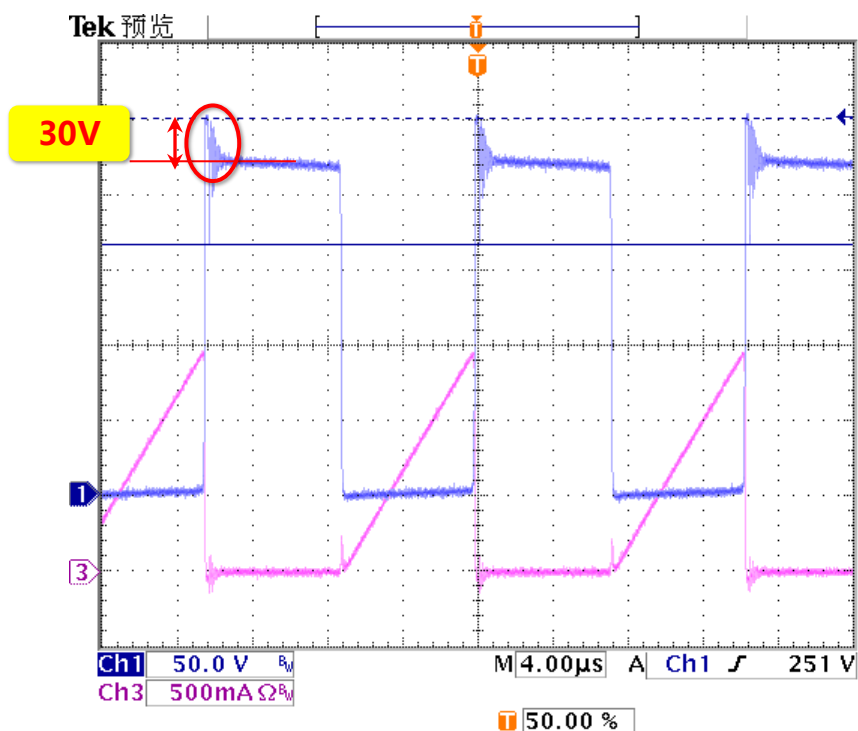
(16.5)025M3GRN			
NONE	6		0.1U-2
	1※	11	0.1U-2
(16.5)025M1	1	39	0.16U-2
(10)025M1		39	0.16U-2
(16.5)025M3	1	9	0.65U-2
(16.5)025M3	1	39	0.16U-2
(10)025M1		39	0.16U-2
(16.5)025M3	1	9	0.65U-2
(16.5)025M3	1	39	0.16U-2
(10)025M1		39	0.16U-2
NONE			



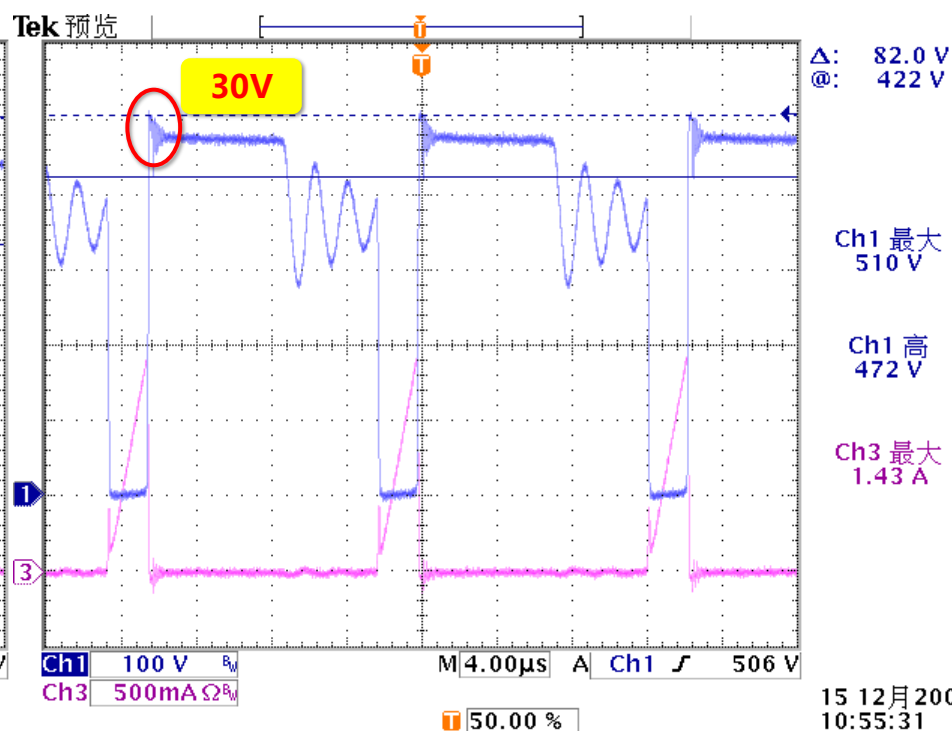


## 实例：24V/35W 70KHz固定频率设计

### 实际工作波形



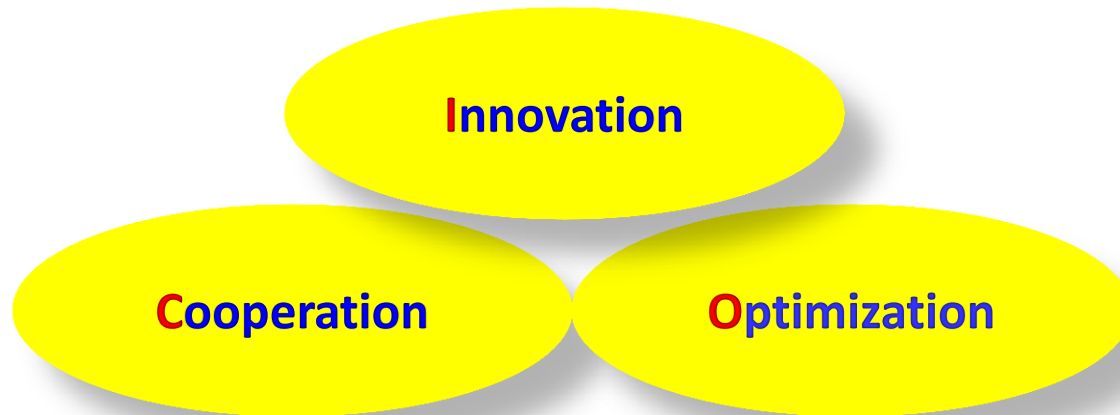
85Vac 24V/35W满载



264Vac 24V/35W满载

15 12月 2008  
10:55:31

# Change the World (Q&A)



## Thank you !